

Substitute for form 1449A/PTO (modified) INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary) Page 1 of 2	Applicati n Number	---
	Filing Date	N v mber 20, 2003
	First Named Invent r	Theiss, Stev n D
	Art Unit	---
	Examiner Name	---
	Attorney Case Number	57389US004

U.S. Patent Documents					
Exam. Init.*	Cite No.	Document Number	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	(This field is not required Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Doc. Number-(Kind Code if Known) (Add Kind Code after patent No. when available)			
SDG	A1	US- 2002/0195929 A1	12/26/2002	Haase et al.	
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Foreign Patent Documents							
Exam. Init.*	Cite No.	Foreign Patent Document		Publication Date MM-DD-YYYY	(This field is not required) Name of Patentee or Applicant of Cited Document	(This field is not required) Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Translation (Check if yes)
		Ctry. Code	Number-KindCode (if known)				
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SDG	B4	WO	00/10196	02/24/2000			
	B5						
	B6						
	B7						

*Examiner: <i>K. D. G.</i>	Date Considered: <i>5/25/04</i>
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

Substitute for form 1449/APTO (modified) INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary) Page 2 of 2	Applicant Number	---
	Filing Date	November 20, 2003
	First Named Inventor	Theiss, Steven D
	Art Unit	---
	Examiner Name	---
	Attorney Case Number	57389US004

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS		
Exam. Init.	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published
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*Examiner: <i>Dr. B</i>	Date Considered: <i>5/29/04</i>
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